

## Rad-hard plastic Quad two-input AND gate

TSSOP-20

[Maturity status link](#)[LEOAC08](#)

### Features

- AND gate
- 1.65 V to 6 V operating supply
- 7 V max. rating
- 8.5 ns propagation delay
- Nickel/Palladium/Gold-lead-finished (NiPdAu), whisker-free
- Gold-wires
- RML < 1% and CVCM < 0.1% guaranteed outgassing
- 50 krad (Si) Total Ionizing Dose
- SEL-free up to 62.5 MeV.cm<sup>2</sup>/mg
- Mass: 80 mg
- Compliant with ST-LEO-specification

### Applications

- Low earth orbit (LEO) applications

### Description

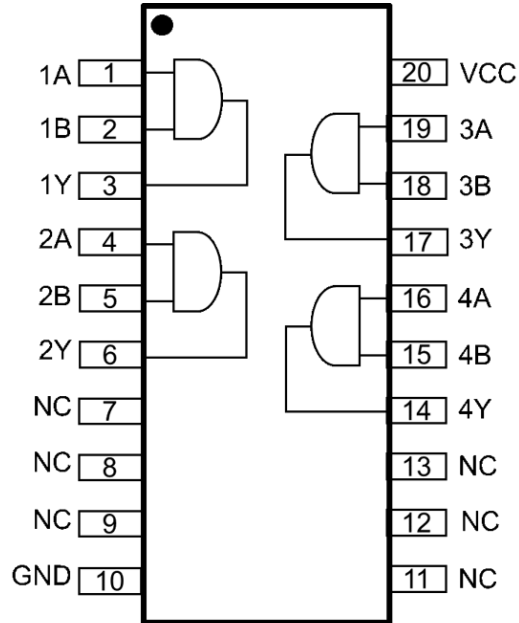
The **LEOAC08** is a CMOS low power quad 2-input AND gate qualified for use in aerospace environments. It operates from 1.65 V to 6 V power supply (7 V absolute maximum rating).

The **LEOAC08** can operate over a large temperature range of -40 °C to +125 °C and it is housed in plastic TSSOP-20, Thin-Shrink Small Outline Package, 20 leads, using golden bonding and Nickel/Palladium/Golden-lead-finishing to prevent whiskers.

The **LEOAC08** is compliant with ST-LEO-specification, dedicated specification for space-ready rad-hard plastic products. This AEC-Q100-based specification offers a specific trade-off between footprint size savings, cost of ownership and quality assurance together with radiation hardness and large quantity capability.

# 1 Functional description

Figure 1. Pin connections (top view)



NC: not internally connected.

The pin can be externally connected to any potential.

Table 1. Truth table

| Each gate |           |            |
|-----------|-----------|------------|
| INPUT (A) | INPUT (B) | OUTPUT (Y) |
| L         | L         | L          |
| L         | H         | L          |
| H         | L         | L          |
| H         | H         | H          |

with: L = low level, H = high Level.

For all inputs,  $V_{IN} = V_{IH}$  minimum or  $V_{IL}$  maximum, verify output  $V_{OUT}$ .

## 2 Maximum ratings and operating conditions

**Table 2. Absolute maximum ratings**

| Symbol         | Parameter  | Value                                 | Unit |
|----------------|--|---------------------------------------|------|
| $V_{CC}^{(1)}$ | Maximum power supply between $V_{CC}$ and GND            | -0.5 to 7                             | V    |
| $V_{IN}$       | DC input voltage range                                   | -0.5 to $V_{CC} + 0.5$ (and 7 V max.) | V    |
| $V_{OUT}$      | DC output voltage range                                  | -0.5 to $V_{CC} + 0.5$ (and 7 V max.) | V    |
| $I_K$          | I/O clamp diode current                                  | +/-20                                 | mA   |
| $T_{stg}$      | Maximum temperature storage                              | -65 to +150                           | °C   |
| $T_j^{(2)}$    | Maximum junction temperature                             | +150                                  | °C   |
| $R_{th}^{(3)}$ | Junction to ambient thermal resistance ( $\Theta_{ja}$ ) | 80                                    | °C/W |
|                | Junction to case thermal resistance ( $\Theta_{jc}$ )    | 17                                    | °C/W |
| ESD            | HBM (human body model)                                   | 2k                                    | V    |
|                | CDM (charged device model)                               | 1k                                    | V    |

1. All voltages, except differential I/O bus voltage, are with respect to the network ground terminal .
2. Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions as per the method 5004 of MIL-STD-883.
3. Short-circuits can cause excessive heating. Destructive dissipation can result from short-circuits on the amplifiers.

**Table 3. Operating conditions**

| Symbol    | Parameter                 | Min. | Max.     | Unit |
|-----------|---------------------------|------|----------|------|
| $V_{CC}$  | Analog supply voltage     | 1.65 | 6        | V    |
| $V_{IN}$  | Input voltage range       | 0    | $V_{CC}$ | V    |
| $V_{OUT}$ | Output voltage range      | 0    | $V_{CC}$ | V    |
| $T_a$     | Ambient temperature range | -40  | +125     | °C   |

**Note:** All unused inputs must be held at  $V_{CC}$  or GND to ensure proper device operation.

### 3 Electrical characteristics

$V_{CC} = 3\text{ V}$  to  $5.5\text{ V}$ , typical values are at ambient  $T_a = +25\text{ }^\circ\text{C}$ , min. and max. values are at  $T_a = -40\text{ }^\circ\text{C}$  and  $+125\text{ }^\circ\text{C}$ , unless otherwise specified.

**Table 4. Electrical characteristics**

| Symbol         | Parameter                    | Test condition   | VCC (V) | Min. | Typ. | Max. | Unit |
|----------------|------------------------------|--|---------|------|------|------|------|
| $V_{OH}^{(1)}$ | High level output voltage    | For all inputs affecting output under test, $V_{IN} = V_{IH}$ minimum or $V_{IL}$ maximum. For all other inputs, $V_{IN} = V_{CC}$ or GND, $I_{OH} = -50\text{ }\mu\text{A}$ | 3       | 2.9  |      |      | V    |
|                |                              |  | 4.5     | 4.4  |      |      |      |
|                |                              |  | 5.5     | 5.4  |      |      |      |
|                |                              | For all inputs affecting output under test, $V_{IN} = V_{IH}$ minimum or $V_{IL}$ maximum. For all other inputs, $V_{IN} = V_{CC}$ or GND, $I_{OH} = -12\text{ mA}$          | 3       | 2.4  |      |      |      |
|                |                              |  | 4.5     | 3.7  |      |      |      |
|                |                              |  | 5.5     | 4.7  |      |      |      |
| $V_{OL}^{(1)}$ | Low level output voltage     | For all inputs affecting output under test, $V_{IN} = V_{IH}$ minimum or $V_{IL}$ maximum. For all other inputs, $V_{IN} = V_{CC}$ or GND, $I_{OL} = +50\text{ }\mu\text{A}$ | 3       |      | 0.1  |      | V    |
|                |                              |  | 4.5     |      | 0.1  |      |      |
|                |                              |  | 5.5     |      | 0.1  |      |      |
|                |                              | For all inputs affecting output under test, $V_{IN} = V_{IH}$ minimum or $V_{IL}$ maximum. For all other inputs, $V_{IN} = V_{CC}$ or GND, $I_{OL} = +12\text{ mA}$          | 3       |      | 0.5  |      |      |
|                |                              |  | 4.5     |      | 0.5  |      |      |
|                |                              |  | 5.5     |      | 0.5  |      |      |
| $I_{OH}$       | High level output current    |  | 3       | -12  |      |      | mA   |
|                |                              |  | 4.5     | -24  |      |      |      |
|                |                              |  | 5.5     | -24  |      |      |      |
| $I_{OL}$       | Low level output current     |  | 3       |      |      | 12   | mA   |
|                |                              |  | 4.5     |      |      | 24   |      |
|                |                              |  | 5.5     |      |      | 24   |      |
| $V_{IH}^{(2)}$ | High level input voltage     |  | 3       | 2.1  |      |      | mA   |
|                |                              |  | 4.5     | 3.15 |      |      |      |
|                |                              |  | 5.5     | 3.85 |      |      |      |
| $V_{IL}^{(2)}$ | Low level input voltage      |  | 3       |      |      | 0.9  | V    |
|                |                              |  | 4.5     |      |      | 1.35 |      |
|                |                              |  | 5.5     |      |      | 1.65 |      |
| $V_{IC+}$      | Positive input clamp voltage | For input under test, $I_{IN} = -1.0\text{ mA}$  | 0       | 0.4  |      | 1.5  | V    |

| Symbol   | Parameter                                    | Test condition  | VCC (V) | Min. | Typ. | Max. | Unit |
|--|--|---|---------|------|------|------|------|
| V <sub>IC-</sub>                                 | Negative input clamp voltage                 | For input under test, I <sub>IN</sub> = -1.0 mA   | Open    | 0.4  |      | 1.5  | V    |
| I <sub>IH</sub>                                  | Input current high                           | For input under test, V <sub>IN</sub> = V <sub>CC</sub><br>For all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND | 5.5     |      |      | 1    | μA   |
| I <sub>IL</sub>                                  | Input current low                            | For input under test, V <sub>IN</sub> = GND<br>For all other inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND             | 5       |      |      | -1   | μA   |
| I <sub>CCH</sub>                                 | Quiescent supply current, output high        | For all inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0 A   | 5.5     |      |      | 40   | μA   |
| I <sub>CCL</sub>                                 | Quiescent supply current, output low         | For all inputs, V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0 A   | 5.5     |      |      | 40   | μA   |
| C <sub>IN</sub> <sup>(3)</sup>                   | Input capacitance                            | Ta = +25 °C   | 5       |      |      | 10   | pF   |
| C <sub>PD</sub> <sup>(4)</sup><br><sup>(3)</sup> | Power dissipation capacitance                | Ta = +25 °C, F = 1 MHz  | 5       |      |      | 88   | pF   |
| T <sub>r</sub> , T <sub>f</sub>                  | Output rise time and fall time               | C <sub>L</sub> = 2 pF, R <sub>L</sub> = 500 ohm (see Figure 2)  | 3       |      | 3.3  |      | ns   |
|  |  |   | 4.5     |      | 2.7  |      |      |
|  |  | C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 ohm (see Figure 2)   | 3       |      | 4.6  |      |      |
|  |  |   | 4.5     |      | 3.3  |      |      |
| T <sub>PHL</sub> <sup>(5)</sup>                  | Propagation delay time An to Yn, high to low | C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 ohm (see Figure 2)   | 3       | 1    |      | 11.5 | ns   |
|  |  |   | 4.5     | 1    |      | 8.5  |      |
| T <sub>PLH</sub> <sup>(5)</sup>                  | Propagation delay time An to Yn, low to high | C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 ohm (see Figure 2)   | 3       | 1    |      | 12.5 |      |
|  |  |   | 4.5     | 1    |      | 9    |      |

1. The V<sub>OH</sub> and V<sub>OL</sub> tests shall be tested at V<sub>CC</sub> = 3.0 V and 4.5 V. The V<sub>OH</sub> and V<sub>OL</sub> tests are guaranteed, if not tested, for other values of V<sub>CC</sub>. Limits shown apply to operation at V<sub>CC</sub> = 3.3 V, ±0.3 V and V<sub>CC</sub> = 5.0 V ±0.5 V. Tests with input current at +50 mA and -50 mA are performed on only one input at a time with duration not to exceed 10 ms. Transmission driving tests may be performed using V<sub>IN</sub> = V<sub>CC</sub> or GND. When V<sub>IN</sub> = V<sub>CC</sub> or GND is used, the test is guaranteed for V<sub>IN</sub> = V<sub>IH</sub> minimum and V<sub>IL</sub> maximum.
2. The V<sub>IH</sub> and V<sub>IL</sub> tests are not required if applied as forcing functions for V<sub>OH</sub> and V<sub>OL</sub> tests.
3. C<sub>IN</sub> and C<sub>PD</sub> shall be measured only for initial qualification and after process or design changes which may affect capacitance. C<sub>IN</sub> shall be measured between the designated terminal and GND at a frequency of 1 MHz. C<sub>PD</sub> shall be tested in accordance with the latest revision of JEDEC Standard JESD20 and table IA herein. For C<sub>IN</sub> and C<sub>PD</sub>, test all applicable pins on five devices with zero failures.
4. Power dissipation capacitance (C<sub>PD</sub>) determines both the power consumption (P<sub>D</sub>) and dynamic current consumption (IS). Where: P<sub>D</sub> = (C<sub>PD</sub> + C<sub>L</sub>) (V<sub>CC</sub> × V<sub>CC</sub>) f + (I<sub>CC</sub> × V<sub>CC</sub>) and IS = (C<sub>PD</sub> + C<sub>L</sub>) V<sub>CC</sub> × f + I<sub>CC</sub>, and f is the frequency of the input signal and C<sub>L</sub> is the external output load capacitance.
5. For propagation delay tests, all paths are tested. The AC limits at V<sub>CC</sub> = 5.5 V are equal to the limits at V<sub>CC</sub> = 4.5 V and guaranteed by testing at V<sub>CC</sub> = 4.5 V. The AC limits at V<sub>CC</sub> = 3.6 V are equal to the limits at V<sub>CC</sub> = 3.0 V and guaranteed by testing at V<sub>CC</sub> = 3.0 V. Minimum AC limits for V<sub>CC</sub> = 5.5 V and V<sub>CC</sub> = 3.6 V are 1.0 ns and guaranteed by guard banding the V<sub>CC</sub> = 4.5 V and V<sub>CC</sub> = 3.0 V minimum limits, respectively, to 1.5 ns. For propagation delay tests, all paths must be tested.

## 4 Waveform and test circuit

Figure 2. Waveform

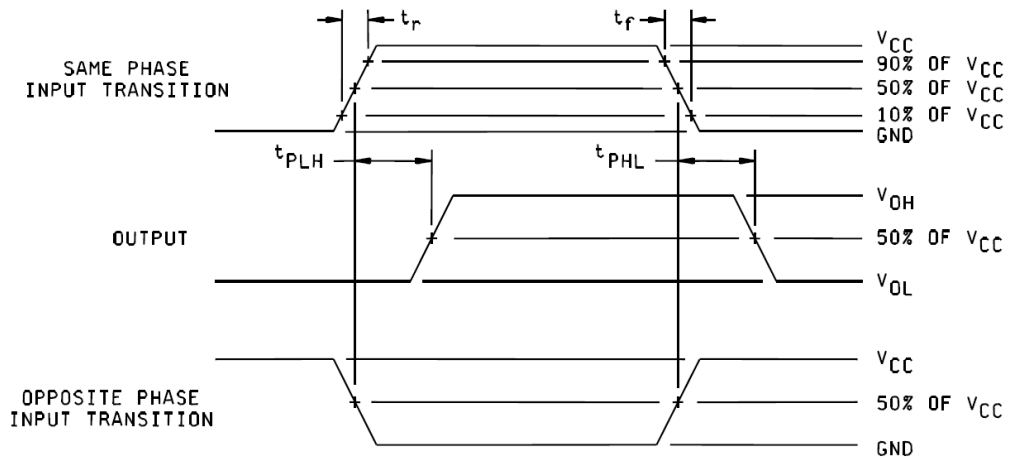
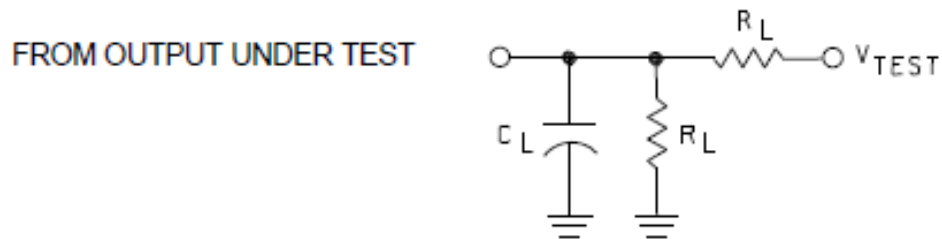


Figure 3. Test circuit



Note:

- $V_{TEST}$  = open for  $t_{PLH}$  and  $t_{PHL}$ .
- $C_L$  = 50 pF or equivalent (includes probe and jig capacitance).
- $R_L$  = 500-ohm or equivalent.
- Input signal from pulse generator:  $V_{IN} = 0.0$  V to  $V_{CC}$ ;  $P_{RR} < 1$  MHz;  $Z_0 = 50$ -ohm;  $t_r < 3.0$  ns;  $t_f < 3.0$  ns;  $t_r$  and  $t_f$  shall be measured from 10% of  $V_{CC}$  to 90% of  $V_{CC}$  and from 90% of  $V_{CC}$  to 10% of  $V_{CC}$ , respectively; duty cycle = 50 percent.
- Timing parameters shall be tested at a minimum input frequency of 1 MHz.
- The outputs are measured one at a time with one transition per measurement.

## 5 Radiations

### Total ionizing dose (TID):

For the qualification, the product is characterized in TID as per MIL-STD-883 TM 1019 up to 50 krad (Si) on 5 biased parts at high dose rate, such a rate being the worst condition for a pure CMOS technology.

All parameters provided in Table 1 apply to both pre- and post-irradiation.

Each new production lot is tested at high dose rate as per MIL-STD-883 TM 1019 on 5 parts.

### Heavy-ions:

Single Event Latchup (SEL) is characterized at 125 °C at a LET of 62.5 MeV.cm<sup>2</sup>/mg. The test shows the product is immune to heavy ions at this LET. Heavy-ion trials are performed on qualification lots only.

The results in radiation are summarized in Table 5 as follows.

**Table 5. Radiations**

| Type               | Conditions  | Results   |
|--------------------|---|---|
| TID <sup>(1)</sup> | <ul style="list-style-type: none"> <li>High-dose rate (40 krad (Si) / h)</li> <li>Temperature: 25 °C</li> <li>Performed on 5 biased parts</li> </ul>  | Within Table 1 up to 50 krad(Si)  |
| SEL <sup>(2)</sup> | <ul style="list-style-type: none"> <li>LET: 62.5 MeV.cm<sup>2</sup>/mg (Xenon ions)</li> <li>Temperature: 125 °C</li> <li>Fluence: 1 x 10<sup>7</sup> ions/cm<sup>2</sup> (10 Million of particles per cm<sup>2</sup>)</li> <li>Normal incidence</li> </ul> | Immune to SEL up to 62.5 MeV.cm <sup>2</sup> /mg<br>(extracted from the LEOAC00, by similarity of architecture) |

1. A total ionizing dose (TID) of 50 krad(Si) is equivalent to 500 Gy(Si), (1 gray = 100 rad).

2. SEL: single event latch-up

## 6 Outgassing

| Specification (tested per ASTM E 595)                         | Value | Unit |
|---|-------|------|
| Recovered mass loss (RML) <sup>(1)</sup>                      | 0.06  | %    |
| Collected volatile condensable material (CVCM) <sup>(2)</sup> | 0.00  | %    |

1. RML < 1%
2. CVCM < 0.1%



## 7 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 7.1 TSSOP-20 package information

Figure 4. TSSOP-20 package outline

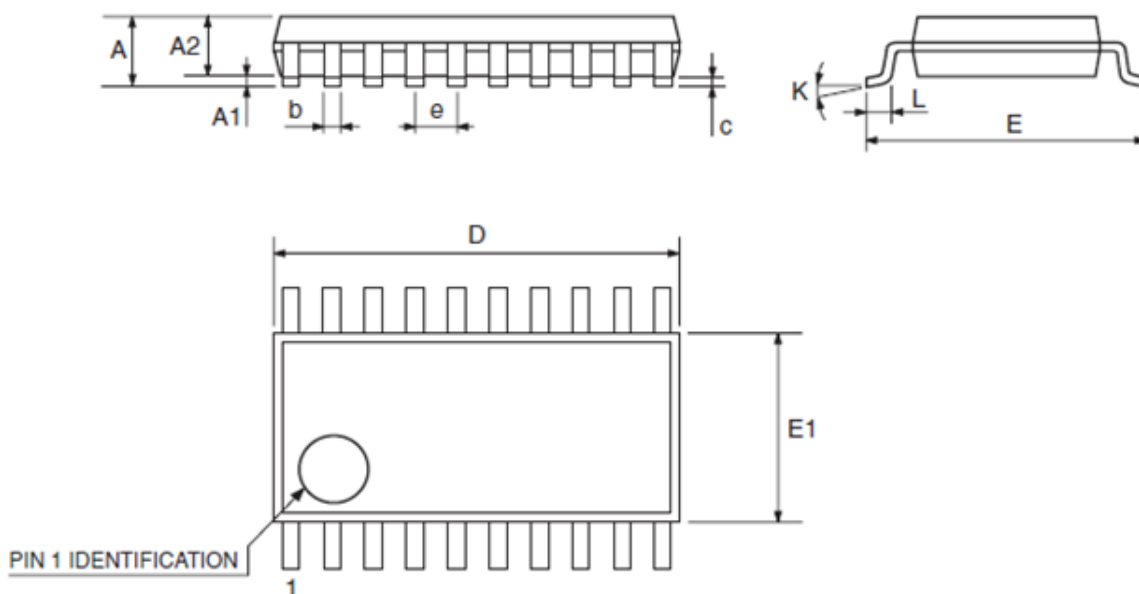


Table 6. TSSOP-20 package mechanical data

| Symbol | Millimeters |          |      | Inches <sup>(1)</sup> |            |       |
|--------|-------------|----------|------|-----------------------|------------|-------|
|        | Min.        | Typ.     | Max. | Min.                  | Typ.       | Max.  |
| A      |             |          | 1.2  |                       |            | 0.047 |
| A1     | 0.05        |          | 0.15 | 0.002                 | 0.004      | 0.006 |
| A2     | 0.8         | 1        | 1.05 | 0.031                 | 0.039      | 0.041 |
| b      | 0.19        |          | 0.30 | 0.007                 |            |       |
| c      | 0.09        |          | 0.20 | 0.004                 |            |       |
| D      | 6.4         | 6.5      | 6.6  | 0.252                 | 0.256      | 0.260 |
| E      | 6.2         | 6.4      | 6.6  | 0.244                 | 0.252      | 0.260 |
| E1     | 4.3         | 4.4      | 4.48 | 0.169                 | 0.173      | 0.176 |
| e      |             | 0.65 BSC |      |                       | 0.0256 BSC |       |
| K      | 0°          |          | 8°   | 0°                    |            | 8°    |
| L      | 0.45        | 0.60     | 0.75 | 0.018                 | 0.024      | 0.030 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Note: TSSOP: Thin-Shrink Small Outline Package, using golden bonding and Nickel/Palladium/Golden-lead-finishing.

## 7.2 TSSOP-20 packing information

Figure 5. TSSOP-20 Carrier tape (dimensions in mm) outline

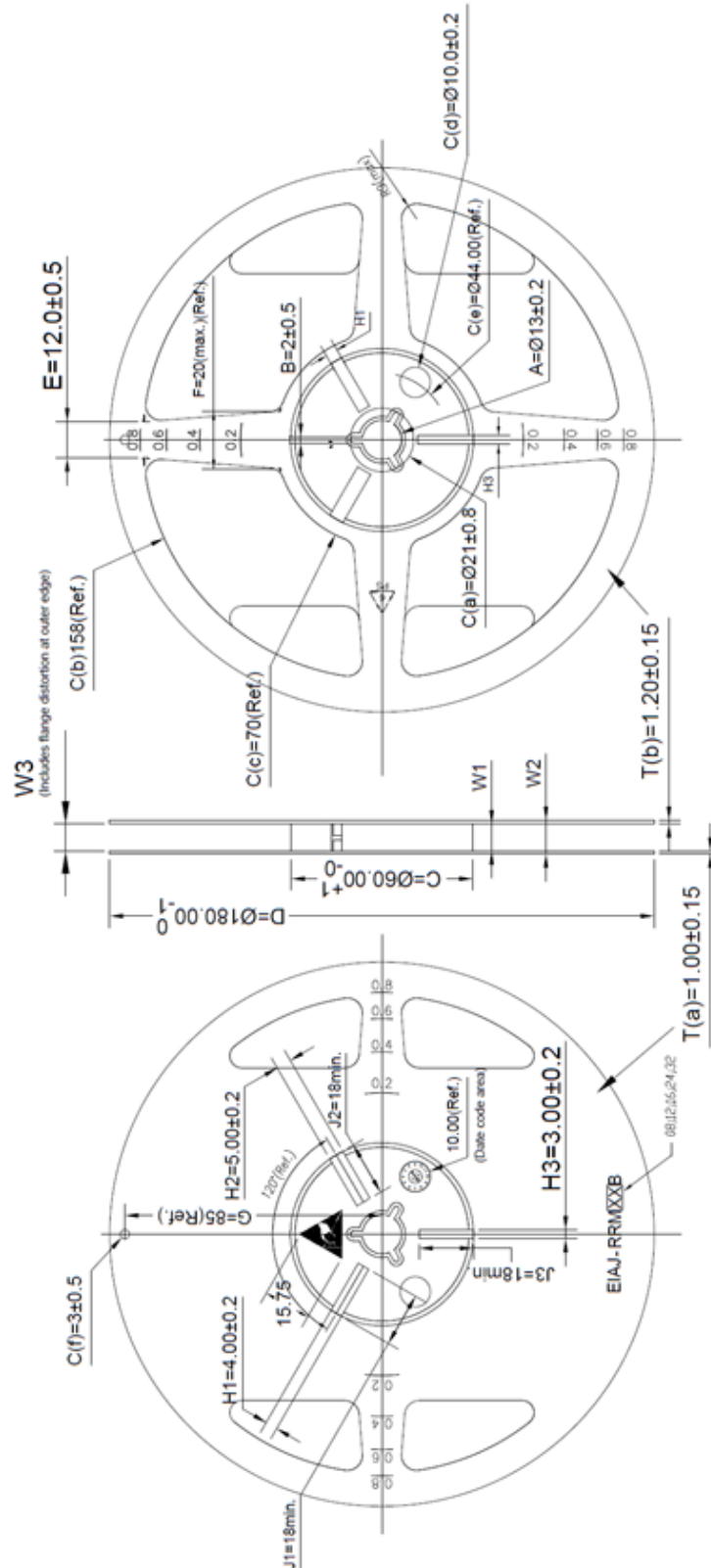
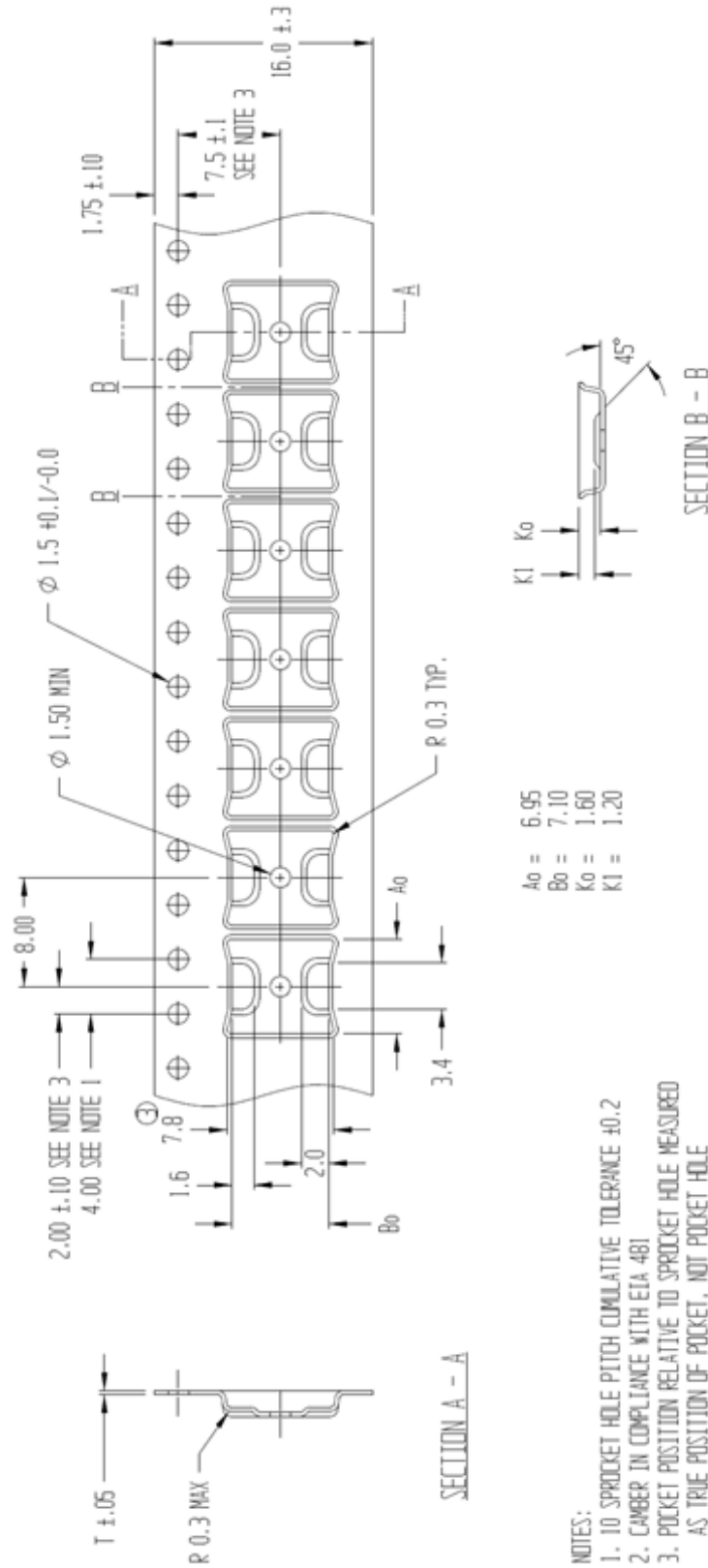


Figure 6. TSSOP-20 tape (dimensions in mm) outline



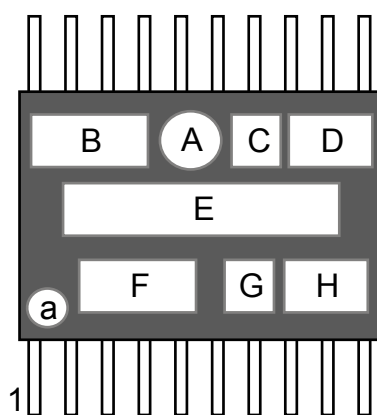
## 8 Ordering information

**Table 7. Ordering information**

| Order code  | Quality level      | Package  | Lead-finish | Marking  | Packing       |
|-------------|--------------------|----------|-------------|----------|---------------|
| LEOAC08PT-D | Development sample | TSSOP-20 | NiPdAu      | DLEOAC08 | Tape and reel |
| LEOAC08PT   | Flight model       | TSSOP-20 | NiPdAu      | LEOAC08  | Tape and reel |

**Table 8. Order code**

| LEO               | AC08 | P                | T             |
|-------------------|------|------------------|---------------|
| LEO qualification | Name | TSSOP-20 package | Tape and reel |

**Figure 7. TSSOP-20 marking**


- a: pin-1 reference
- A : Second Level of interconnexion (type of lead-finishing)
- B: ST logo
- C: Assy plant
- D: Lot code
- E: Marking area
- F: Country of origin
- G: Assy year
- H: Assy week

## Revision history

**Table 9. Document revision history**

| Date        | Version | Changes  |
|-------------|---------|--|
| 10-Jan-2022 | 1       | First release.   |
| 01-Feb-2022 | 2       | Removed footnote in Table 7. Ordering information.         |
| 04-Oct-2024 | 3       | Updated minimum operating power supply from 2 V to 1.65 V. |

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